	ANSMISSION BY FA	ACSIMILE (37 CFR 1.8)	Docket No. F1S920030278US1	
Application No. (8/707,047	Filing Date 11/18/2003	Examiner I., VAN	Group Art Unit 1753	
nvention: METHOD FOR TEANIUM-TUNGSTEN S		PLATING OF SEMICONDUCTO	OR DEVICE I/O PADS USING	
I hereby certify that this is being facsimile transmitte	ed to the United States Par	Transmittal and Amendment (Identify type of correspondence) tent and Trademark Office (Fax.	No. 571-273-8300	
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AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): TIEN-JEN CHANG ET AL.						Docket No. F1S920030278US1		
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Application No.	Filing Date	Examiner	, ,	Customer N	40.	Group Art Unit	4	
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Invention: METHOD FOR SELECTIVE ELECTRO-PLATING OF SEMICONDUCTOR DEVICE I/O PADS USING A TITANIUM-TUNGS SEED LAYER								
		COMMISSIONER FO						
Transmitted herew	with is an amendment in	in the above-identified	application	on.				
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	y	CLAIMS AS AN	MENDER)				
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Multiple Dependen	nt Claims (check if appl	olicable)				***	\$0.00	
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	TIEN-JEN CHANG, ET AL.)
Serial No.:	10/707,047) Group Art Unit: 1753
Filed:	November 18, 2003) Examiner: Van, L.
For:	METHOD FOR SELECTIVE ELECTRO- PLATING OF SEMICONDUCTOR DEVICE I/O PADS USING A TITANIUM-TUNGSTEN SEED LAYER)) Confirmation No.: 1046)

AMENDMENT AFTER FINAL

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

In response to the Final Office Action mailed February 27, 2006, please amend the Application as follows: